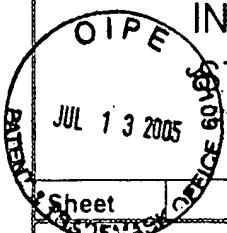


Substitute for Form 1449/PTO

**Complete if Known**

Application Number	10/816,311
Filing Date	3/31/2003
First Named Inventor:	Nick Lindert
Art Unit	2815
Examiner Name	Nguyen, Joseph



# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

*(use as many sheets as necessary)*

Sheet 1 of 2 Attorney Docket Number 42P18257

**U.S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code <sup>2</sup> (if known)				
JN		US-	20040031979 A1	02/19/2004	Lochtefeld et al.	
		US-	6,716,684 B1	4/6/2004	Krivokapic et al.	
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		US-	6,376,317 B1	4/23/2002	Forbes et al.	

**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Country Code <sup>3</sup>	Number <sup>4</sup> Kind Code <sup>5</sup> (if known)				
JN		EP	0 623 963 A1	11/9/1994	Siemens AG		
JN		WO	02/43151A	5/30/2002	Hitachi ULSI Sys Co Ltd		

Examiner Signature	JOSEPH NGUYEN	Date Considered	9/13/05
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Application Number	10/816,311
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First Named Inventor:	Nick Lindert
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Sheet	2	42P18257	2	Attorney Docket Number	42P18257
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## NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T <sup>2</sup>
JN		T. Park et al., "Fabrication of Body-Tied FinFETs (Omega MOSFETS) Using Bulk Si Wafers", 2003 Symposia on VLSI Technology Digest of Technical Papers, June 2003, pages 135-136.	
		V. Subramanian et al., "A Bulk-Si-Compatible Ultrathin-body SOI Technology for Sub-100nm MOSFETS" Proceeding of the 57th Annual Device Research Conference, pp. 28-29 (1999)	
		Hisamoto et al., "A Folded-channel MOSFET for Deepsub-tenth Micron Era", 1998 IEEE International Electron Device Meeting Technical Digest, pp 1032-1034 (1998)	
		Huang et al., "Sub 50-nm FinFET: PMOS", 1999 IEEE International Electron Device Meeting Technical Digest, pp 67-70 (1999)	
		Auth et al., "Vertical, Fully-Depleted, Surroundings Gate MOSFETS On sub-0.1um Thick Silicon Pillars", 1996 54th Annual Device Research Conference Digest, pp 108-109 (1996)	
		Hisamoto et al., "A Fully Depleted Lean-Channel Transistor (DELTA)-A Novel Vertical Ultrathin SOI MOSFET", IEEE Electron Device Letters, V. 11(1), pp36-38 (1990).	
		Jong-Tae Park et al., "Pi-Gate SOI MOSFET" IEEE Electron Device Letters, Vol. 22, No. 8, August 2001, pages 405-406	
		Hisamoto, Digh et al. "FinFET- A Self-Aligned Double-Gate MOSFET Scalable to 20 nm", IEEE Transactions on Electron Devices, Vol. 47, No. 12, December 2000, pages 2320-2325	
		International Search Report PCT/US 03/26242	
		International Search Report PCT/US 03/39727	
		International Search Report PCT/US 03/40320	

Examiner Signature	<i>JOSEPH NGUYEN</i>	Date Considered	9/17/05
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